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Fabrication of Fe₂O₃ nanowire arrays based on oxidation-assisted stress-induced atomic-diffusion and their photovoltaic properties for solar water splitting

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In this research, we propose a new simple method to fabricate high-density Fe₂O₃ nanowire arrays for solar water splitting, based on oxidation-assisted stress-induced atomic-diffusion. In the presence of water vapor, surface oxidation was promoted during the heating process. The driving force induced by the stress gradient was enhanced due to the expansion of the oxidation layer. Therefore, Fe₂O₃ nanowire arrays were fabricated at a relative low temperature (350 °C) with a high density (8.66 wire per μm²). Using the nanowire array as the photoanode, a photocurrent density of 0.65 mA cm⁻² at 1.23 V vs. RHE was achieved in a three-electrode system.

1. Introduction

Nowadays, most of the energy consumed by human beings comes from fossil fuel. Fossil fuel is not an ideal energy resource for the future due to several disadvantages, such as the limited amount, which cannot satisfy the energy demands in the future; moreover, the combustion of fossil fuel produces CO₂, one of the main greenhouse gases. As a sustainable clean energy source, hydrogen is an ideal choice for the future. Photoelectrochemical solar fuel production, especially solar water splitting, has been attracting increasing interest, motivated by the recent advances in nanostructured materials and by concerns over the environmental impact of fossil fuels.¹

Solar water splitting uses only water and solar energy and a catalyst to produce hydrogen. Some semiconductors have shown great potential for this application, such as BiVO₄, TiO₂, and Fe₂O₃ with the theoretical maximum solar to hydrogen (STH) efficiencies of 9.2%, 2.0%, and 15%, respectively.² Fe₂O₃ is the most promising of these materials due to the small bandgap and the related visible light absorption, natural abundance, low cost, and stability under deleterious chemical conditions. Recently, several reports on doped nanostructure Fe₂O₃ used for solar water splitting have been published. For example, in 2006, Cesar *et al.* fabricated the silicon-doped thin hematite film, with the solar to hydrogen conversion efficiency of 2.1%.³ In 2008, Hu *et al.* reported a platinum-doped thin hematite film with a photocurrent density of 1.43 mA cm⁻², at 0.4 V vs. Ag/AgCl.⁴ In 1999,

a nanocrystalline n-Fe₂O₃ thin-film was synthesized by Khan *et al.* with a photocurrent density of 3.7 mA cm⁻² at 0.7 V vs. saturated calomel electrode (SCE).⁵ In 2009, Mohapatra *et al.* used a sono-electrochemical anodization method to grow Fe₂O₃ nanotube arrays on an Fe plate with a photocurrent density of 1.41 mA cm⁻² at 0.5 V vs. Ag/AgCl.⁶

On the other hand, Fe₂O₃ nanowire arrays can be fabricated by stress-induced method, as reported previously.⁷ Nanowire array structure was considered having two advantages used for solar water splitting. The first is that due to the high surface to volume ratio of nanowire structure, it could provide large electrode/electrolyte interface area to enhance the chemical reaction, thereby improving the water splitting performance eventually. The second is that nanowire array could absorb more light energy than the other structures such as thin film or nanoparticles because the nanowire array is in a 3D structure which can absorb not only the incident light but also the reflected one. Fe₂O₃ nanowire arrays can be obtained by heating a high-purity iron substrate under ambient conditions, which is a simple and low-cost method. However, because the density of these nanowire arrays is not high enough, they are unfavorable for solar water splitting. In this work, a new method is proposed to synthesize high-density Fe₂O₃ nanowire arrays on an iron plate, under low-temperature conditions used for solar water splitting. In the presence of water vapor, surface oxidation was promoted during the heating process, thereby enhancing the driving force induced by stress gradient due to the expansion of the oxidation layer. Consequently, it is possible to fabricate high-density Fe₂O₃ nanowire arrays at a relatively low temperature (350 °C) compared to that used in the traditional method (500–800 °C).^{8,9}

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2. Experimental

2.1 Nanowire fabrication

Commercial iron plate with the purity of 99.95% was used as the substrate for the nanowire fabrication. The thickness of the iron plate is 0.1 mm and the size of each substrate is 10 mm × 10 mm.

The iron plate was heated by a ceramic heater in an atmosphere of water vapor. In order to find the best conditions for the nanowire array fabrication, some key parameters are investigated, which include the heating temperature, heating time, water vapor volume, and the duration of heating. Heating temperature was set between 250 and 700 °C, as shown in Table 1. A humidifier was used to provide the water vapor condition, with a gas flow rate ranging from 0.2 L h⁻¹ to 1.25 L h⁻¹, as shown in Table 2. Heating time of the iron plate on the ceramic heater was set to 30, 60, and 90 min, respectively, as shown in Table 3. After the fabrication, all the samples were analyzed by scanning electron microscopy (SEM, JSM-7000FK) and X-ray diffraction (XRD).

2.2 Photocurrent measurements

Photocurrent measurement was carried out using a three-electrode system, as shown in Fig. 1. The fabricated Fe₂O₃ nanowire array is used as the photoanode, the cathode is a Pt wire with a diameter of 0.05 mm, and Ag/AgCl is used as the reference electrode. These three electrodes were placed in

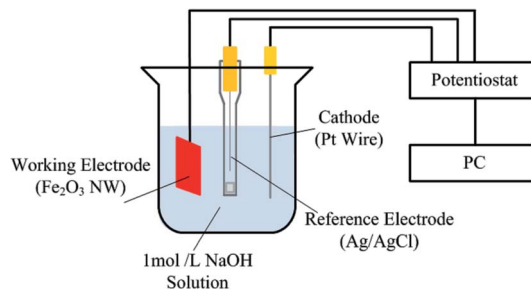


Fig. 1 Schematic of the three-electrode measurement system.

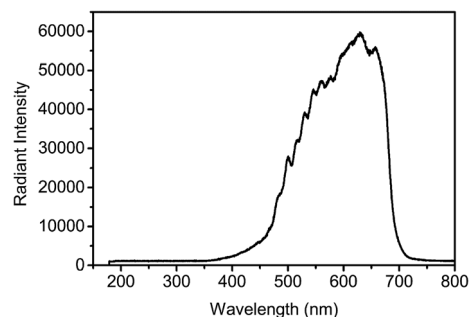


Fig. 2 Spectrum of the halogen light used in photocurrent density measurement.

Table 1 Experimental conditions: different heating temperatures

No.	Heating time (min)	Temperature (°C)	Water vapor volume (L h ⁻¹)
1	90	250	0.2
2		350	
3		450	
4		500	
5		600	
6		700	

Table 2 Experimental conditions: different water vapor volumes

No.	Heating time (min)	Heating temperature (°C)	Water vapor volume (L h ⁻¹)
7	90	450	0.2
8			1
9			1.25

Table 3 Experimental conditions: different heating times

No.	Heating time (min)	Heating temperature (°C)	Water vapor volume (L h ⁻¹)
10	30	450	0.2
11	60		
12	90		

a 1 mol L⁻¹ NaOH solution. The light source is a quartz halogen fiber optic illuminator (Fiber-Lite PL800), the spectrum of the light source was measured as shown in Fig. 2, and the optical power density was measured to be 154 mW cm⁻² by a power meter (COHERENT LM-10).

IPCE measurements were performed using a Xe lamp with the single-wavelength filters from 400 nm to 650 nm. The light energy of the incident light from the lamp was measured with a power meter (COHERENT LM-10). All IPCE measurements were carried out with the applied bias of 0.234 V *versus* Ag/AgCl reference electrode (1.23 V *vs.* RHE).

3. Results and discussion

3.1 Experimental results and discussions

Fig. 3 shows the SEM images of the nanowire arrays fabricated at different heating temperatures under the conditions shown in Table 1. It can be inferred from the SEM images that the morphologies of the nanowires are different under different temperatures, besides the density, length, and diameters of the nanowires. The nanowires heated at 350, 450, and 500 °C (Fig. 3(b), (c) and (d), respectively) are cone-shaped and those heated at 600 °C (Fig. 3(e)) and 700 °C (Fig. 3(f)) are wire-shaped. Similar morphologies are observed for a given temperature, indicating that the heating temperature affects the morphology of the nanowire.

The density of the nanowires is a key factor affecting the efficiency of the solar-hydrogen energy cycle. A comparison of the density of the nanowire arrays fabricated at different temperatures is shown in Fig. 4. The largest density of 14.3 wire



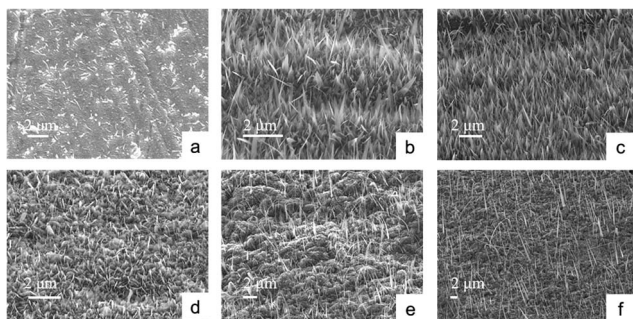


Fig. 3 SEM micrographs of the Fe_2O_3 nanowire arrays obtained at different heating temperatures: (a) 250; (b) 350; (c) 450; (d) 500; (e) 600; and (f) 700 °C.

per μm^2 is achieved for the sample heated at 450 °C. When the iron plate was heated at 250 °C, only a small quantity of the nanowires could be observed on the sample surface. With the increase in the heating temperature, the density of the nanowire array increased up to 450 °C. However, it decreased for temperatures above 450 °C. The density is only 1 wire per μm^2 at 700 °C.

The length and diameter statistics of the nanowires obtained at different temperatures are shown in Fig. 5 and 6, respectively. With the increase in the heating temperature, the average length of the nanowires increased, and the longest nanowires of 9.98 μm average lengths were obtained at 700 °C. Fig. 6 shows the diameter statistic of the nanowires fabricated at different temperatures. Diameters of the nanowires are also considered as an important factor affecting the efficiency of solar to hydrogen energy conversion; nanowires with larger diameters could absorb more light than those with small diameters, which could eventually improve the conversion efficiency. Unlike the variation in the average length, the average diameter of the nanowires decreases with the increase in heating temperature. The largest average diameter of 300 nm was obtained for nanowires fabricated at 250 °C. The effect of the water vapor volume on the nanowire growth was also investigated in this study. The volume of the water vapor was set to be 0.2, 1, and 1.25 L h^{-1} , respectively, as shown in Table 2. From the SEM images shown in Fig. 7, it can be easily observed that the density

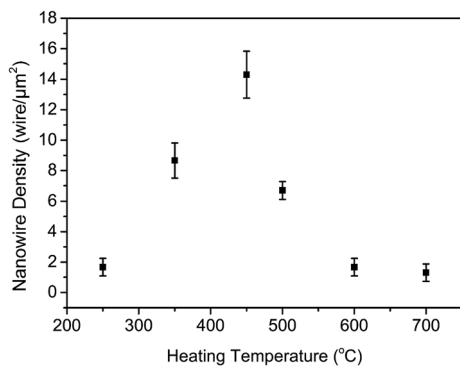


Fig. 4 Density statistic of the Fe_2O_3 nanowires obtained at different temperatures.

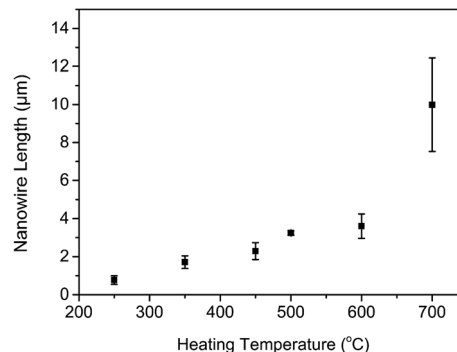


Fig. 5 Length statistic of the Fe_2O_3 nanowires obtained at different temperatures.

of the nanowires decreased with an increase in the water vapor volume.

Fig. 8 shows the results of the iron samples heated for 30, 60, and 90 min, respectively, under the conditions listed in Table 3. When the sample was heated for a very short duration, some weak spots were generated on the iron plate surface, without any nanowire growth (Fig. 8(a)). In the sample heated for 60 min (Fig. 8(b)), nanowires were formed, but with very different lengths and the density was lower than that of the sample heated for 90 min, as shown in Fig. 8(c). The nanowires had the highest density when the sample was heated for 90 min. The experiments were also carried out with longer heating times, 120 and 150 min, but this did not increase the density of the nanowire array.

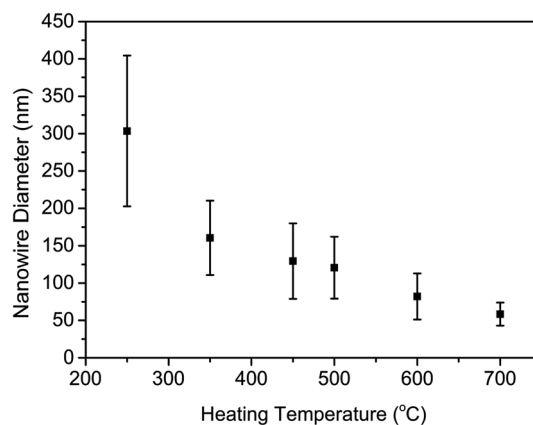


Fig. 6 Diameter statistic of the nanowires obtained at different temperatures.

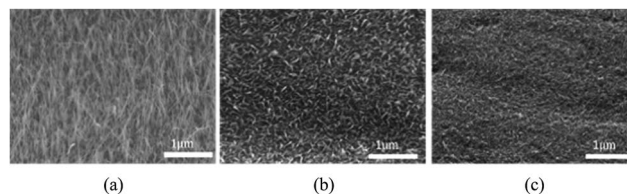


Fig. 7 SEM micrographs of the Fe_2O_3 nanowire arrays for samples heated at 450 °C with different water vapor volumes: (a) 0.2; (b) 1; and (c) 1.25 L h^{-1} .



The cross section of the fabricated sample has also observed by using the FESEM, as shown in Fig. 9. Three layers can be easily observed from the SEM image, which include the nanowire layer, the oxide layer and the iron layer. The morphology of the nanowires fabricated at 450 °C was shown in Fig. 10. The shape of nanowires looks like grass, which indicated that nanowires grew from the top of themselves with the precipitation of diffused Fe atoms and their oxidation. The average diameter of the nanowires shown in Fig. 10 is 144 nm, approximately.

3.2 X-ray diffraction and discussions

Fig. 11 shows the XRD patterns of the nanowire arrays obtained for different heating temperatures under the water vapor condition of 0.2 L h^{-1} and heating time of 90 min. From data obtained from different samples, it can be inferred that when the heating temperature is higher than 450 °C, the formed Fe_2O_3 layer on Fe substrate is thicker than that formed at 450 °C. By comparing the densities of the nanowire arrays, it is considered that although the heating temperature of over 500 °C could provide a larger driving force to increase the diffusion of the Fe atoms, the formed thicker oxidation layer will hinder the growth of the nanowires, due to the decrease of numbers of weak spots in Fe_2O_3 layer. Therefore, low density nanowire arrays were obtained at relative high temperatures. In the case of the sample heated at 450 °C, the oxidization rate of the iron plate surface is optimal, generating more weak spots in Fe_2O_3 layer, and the driving force is also large enough to make the Fe atoms diffuse from the inner part to the Fe/ Fe_2O_3 interface.

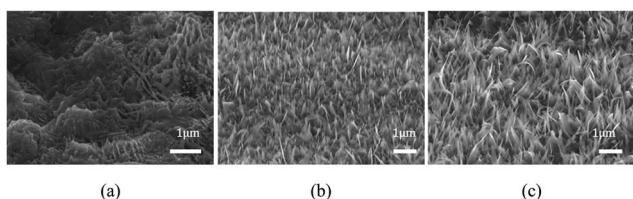


Fig. 8 SEM micrographs of the Fe_2O_3 nanowire arrays fabricated at 450 °C for different heating durations: (a) 30; (b) 60; and (c) 90 min.

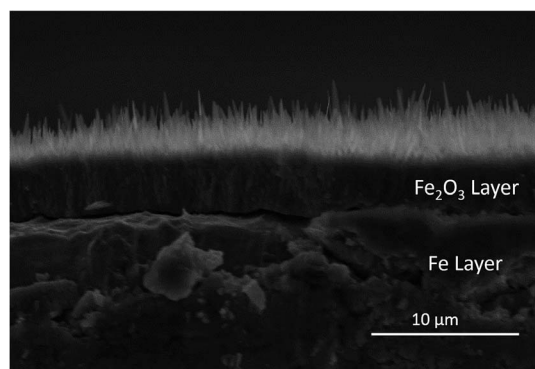


Fig. 9 SEM cross section observation of the Fe_2O_3 nanowire sample.

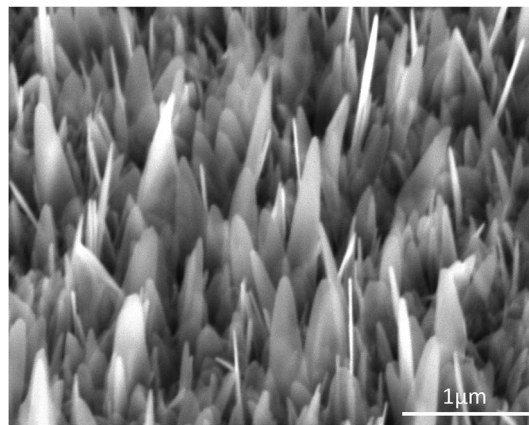


Fig. 10 SEM image of the Fe_2O_3 morphology.

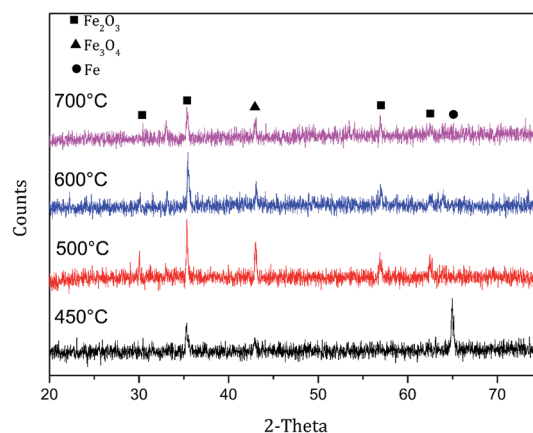


Fig. 11 XRD patterns of the Fe_2O_3 nanowire arrays at different temperatures.

3.3 Photocurrent measurements

The photovoltaic properties of the nanowires have been investigated using a three-electrode system (Fig. 1), and the results are shown in Fig. 12. The Fe_2O_3 nanowire photoanode fabricated at 350 °C showed the largest photocurrent density among all the photoanodes, 0.65 mA cm^{-2} at 1.23 V vs. a reversible hydrogen electrode (RHE). Although the nanowire photoanode fabricated at 450 °C has the largest density of nanowires, the photocurrent density is lower at 0.47 mA cm^{-2} , due to the smaller average diameter of the nanowires (127 nm) compared to that of the nanowire photoanode fabricated at 350 °C (161 nm). The samples heated at 250, 500, 600, and 700 °C show very small photocurrent values, possibly owing to the poor nanowire density.

The incident-photon-to-current efficiency (IPCE) of the nanowire photoanode fabricated at 450 °C was measured to confirm the performance of water splitting, as shown in Fig. 13. The IPCE decreased with the increase of wavelength, and the maximum value is 5.54% at 400 nm. This value is relative high than that of other pure Fe_2O_3 photoanodes without any functional modification, reported by the literatures, such as the



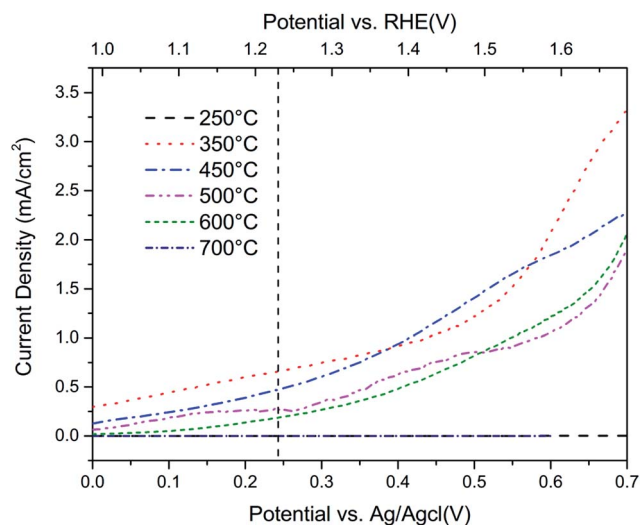


Fig. 12 Photocurrents from the nanowire array anodes obtained at different heating temperatures.

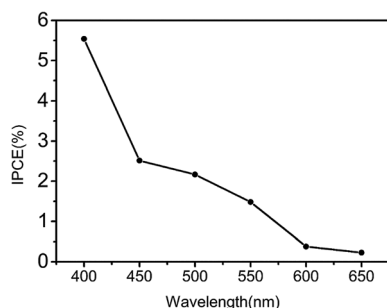


Fig. 13 IPCE of Fe_2O_3 nanowire array photoanode at 0.234 V vs. Ag/AgCl (1.23 V vs. RHE).

Fe_2O_3 film with the IPCE of 2% at 400 nm,¹⁰ and Fe_2O_3 nanorods with the IPCE of 1.3% at 400 nm.¹¹ It should be mentioned that the IPCE value could be remarkably improved by functional modification of the Fe_2O_3 nanowire array. It has been reported that the Pt-doped Fe_2O_3 nanorods can reach the IPCE up to 55% at 400 nm,¹² Pt-doped polycrystalline thin-film electrodes of Fe_2O_3 exhibit an IPCE of 25% at 400 nm,⁴ and Fe_2O_3 thin films

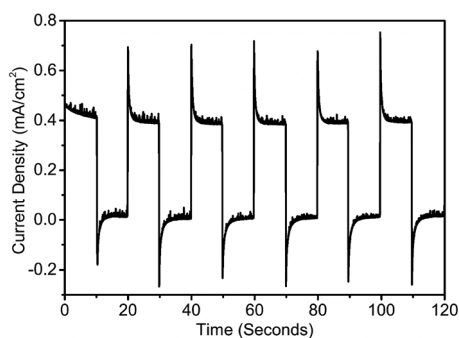


Fig. 14 $J-t$ curve of Fe_2O_3 nanowire array photoanode under chopped illumination at a bias of 0.234 V vs. Ag/AgCl (1.23 V vs. RHE).

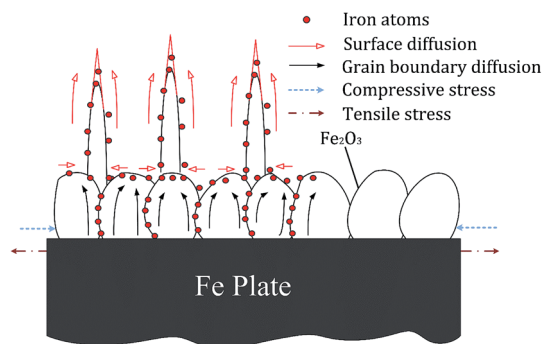


Fig. 15 Schematic of the mechanism of the nanowire growth.

modified with a catalytic cobalt layer has the IPCE of 46% at 370 nm.¹³

The stability of photocurrent was measured at 1.23 V vs. RHE by a chopped illumination with 10 s on/off for 120 seconds, for a Fe_2O_3 nanowire array photoanode fabricated at 450 °C, as shown in Fig. 14. The photocurrent density is very stable and increased and decreased quickly with on and off the light which shows the good photoresponse properties of the Fe_2O_3 nanowire array photoanode.

3.4 Mechanism

When the iron plates are heated, the thermodynamically stable oxide layer, Fe_2O_3 topmost layer are formed. Because the molar volumes of Fe_2O_3 ($30.39 \text{ cm}^3 \text{ mol}^{-1}$)¹⁴ is great larger than that of Fe ($7.09 \text{ cm}^3 \text{ mol}^{-1}$),¹⁴ tensile stress is generated in the iron plate due to the volume expansion of Fe_2O_3 layer.¹⁵ Thus, a stress gradient is generated from the center of the Fe plate to the Fe/ Fe_2O_3 interface. The gradient of stress can serve as the driving force for the atomic diffusion and the atomic flux propagates from the low tensile area to high tensile area. Therefore, with the formation of the Fe_2O_3 layer, the Fe atoms move from the center of Fe plate to Fe/ Fe_2O_3 interface due to the stress-induced atomic diffusion. These diffusion atoms serve as a continuous source for the formation of Fe_2O_3 nanowires.

After the Fe atoms diffuse along the stress gradient to the Fe/ Fe_2O_3 interface, they cumulate at the interface and then find the weak spots of Fe_2O_3 layer and penetrate them to form nanowires accompanying the oxidation of the Fe atoms. After the nanowires are formed, Fe atoms continue to diffuse along the nanowires due to the high driving force (see Fig. 15), which explains the formation of longer nanowires with the increase in the heating time. Under the water vapor condition, greater amounts of iron can be oxidized into Fe_2O_3 , which could increase the thickness of the Fe_2O_3 layer on the Fe substrate. Therefore, the tensile stress that the Fe layer suffered from the Fe_2O_3 layer is much larger in the presence of water vapor than that created under an atmosphere condition. This increase the stress gradient and the driving force for atom diffusion, thereby resulting in an increase in the density of the nanowires. It should be noted that the driving force induced by the stress gradient is due to the volume expansion of the Fe_2O_3 oxidation layer, which is different from that induced by the thermal



expansion mismatch generated in Al/Si¹⁶ or Cu/Si¹⁷ structured samples. The similar thermal expansion coefficients of Fe₂O₃ and Fe make it difficult to create a stress based driving force based on thermal expansion mismatch.

4. Conclusions

In summary, a new oxidation-assisted stress-induced method to fabricate high-density semiconductor nanowire array has been demonstrated. Large area Fe₂O₃ nanowire arrays with high density were fabricated successfully at low temperatures under the water vapor condition. The best growth condition for the Fe₂O₃ nanowire arrays is heating for 90 min at 350 °C, and a water vapor volume of 0.25 L h⁻¹. Both the density and diameter of the nanowires affect the photocurrent density of the nanowire photoanode, which reached 0.65 mA cm⁻² for the nanowire array with the density and diameter of 8.66 wire per μm² and 161 nm, respectively. The photocurrent measurements indicate the good potential of the Fe₂O₃ nanowire array photoanodes for solar water splitting.

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